TOSHIBA Transistor Silicon NPN Triple Diffused Type (PCT process)

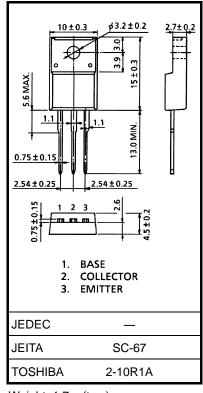
2SC5353

Switching Regulator and High Voltage Switching Applications High-Speed DC-DC Converter Applications

- Excellent switching times: t_r = 0.7 μs (max), t_f = 0.5 μs (max)
- High collectors breakdown voltage: $V_{CEO} = 800 \text{ V}$

Absolute Maximum Ratings (Tc = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V _{CBO}	900	V	
Collector-emitter voltage		V _{CEO}	800	V	
Emitter-base voltage		V _{EBO}	7	V	
Collector current	DC	Ι _C	3	A	
	Pulse	I _{CP}	5		
Base current		Ι _Β	1	А	
Collector power dissipation	Ta = 25°C	Pc	2.0	W	
	Tc = 25°C	ГC	25		
Junction temperature		Тј	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	



Weight: 1.7 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high

temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

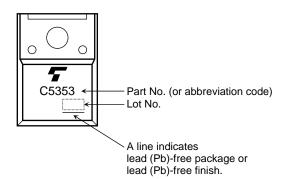
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Unit: mm

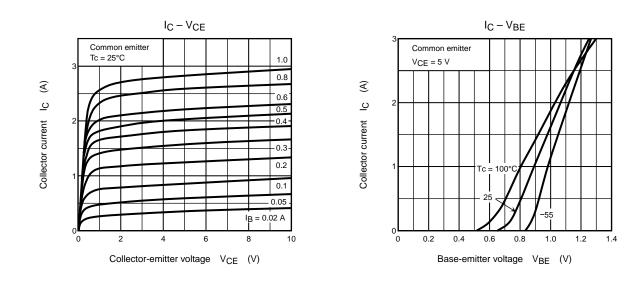
Electrical Characteristics (Tc = 25°C)

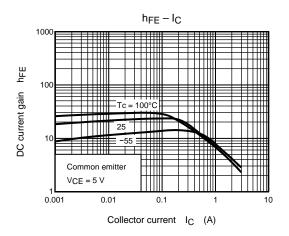
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current		I _{CBO}	$V_{CB} = 720 \text{ V}, \text{ I}_{E} = 0$	_	_	100	μA
Emitter cut-off current		I _{EBO}	$V_{EB} = 7 V, I_{C} = 0$		_	10	μA
Collector-base breakdown voltage		V (BR) CBO	$I_{C} = 1 \text{ mA}, I_{E} = 0$	900	_	_	V
Collector-emitter breakdown voltage		V (BR) CEO	$I_{\rm C} = 10 \text{ mA}, I_{\rm B} = 0$	800	_	_	V
DC current gain		h _{FE (1)}	V _{CE} = 5 V, I _C = 1 mA 10		_	_	
		h _{FE (2)}	V _{CE} = 5 V, I _C = 0.15 A	15	_	_	
Collector-emitter saturation voltage		V _{CE (sat)}	I _C = 1.2 A, I _B = 0.24 A		_	1.0	V
Base-emitter saturation voltage		V _{BE (sat)}	I _C = 1.2 A, I _B = 0.24 A		_	1.3	V
Switching time	Rise time	tr	Output $I_{B1} = 0.24 \text{ A}, I_{B2} = -0.48 \text{ A}, duty cycle} \leq 1\%$	_	_	0.7	
	Storage time	^t stg			_	4.0	μs
	Fall time	t _f		_	_	0.5	

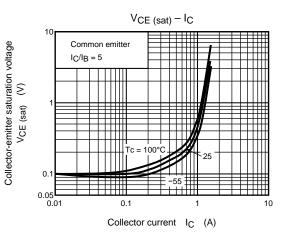
Marking

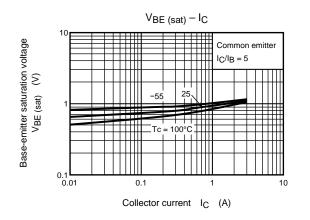


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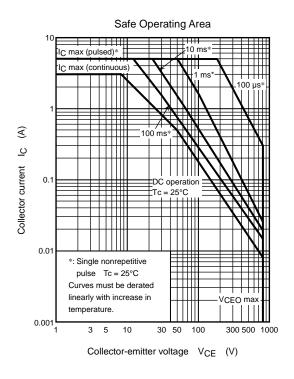


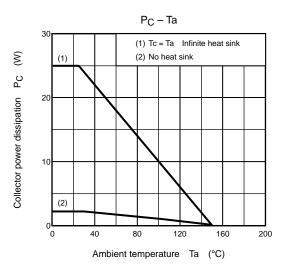
IC = 5IB1 2IB1 = -IB2Pulse width $= 20 \ \mu s$ Duty cycle $\leq 1\%$ Tc = 25°C 10 tsta 0.1 0.01 0.1 10



Switching Characteristics

Switching time (µs)





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20070701-EN

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